

# ULTRA-FAST GLASS PASSIVATED RECTIFIER VOLTAGE RANGE 50 TO 1000 Volts Current 2.0 Ampere

#### **FEATURES**

- \* Ultra-fast recovery time for high efficiency
- \* Glass Passivated Chip junction
- \* Excellent high temperature switching
- \*Low reverse leakage current
- \* Low forward voltage drop
- \* High current capability

# **MECHANICAL DATA**

\* Case: JEDEC DO-15

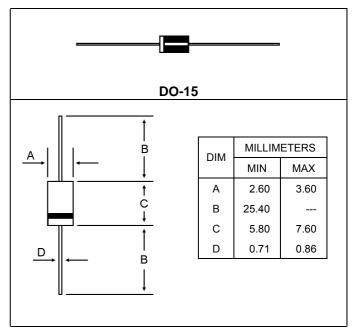
\* Epoxy: UL94V-O rate flame retardant

\* Terminals: Solderable Per MIL-STD-202 Method 208

\* Polarity: Color band denotes cathode end

\* Mounting position: Any

\*Weight: 0.015 ounces, 0.4 grams



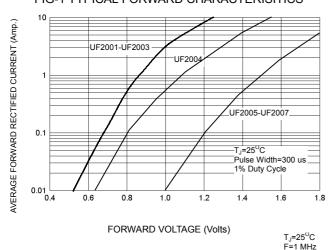
# MAXIMUM RATINGS AND ELECTRICAL CHARATERISTICS

- \* Rating at 25 ambient temperature unless otherwise specified
- \* Single phase-half wave. 60Hz, resistive or inductive load.
- \* For capacitive load derate current dh 20 %

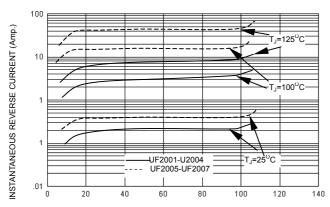
Characteristic	Symbol	UF2001	UF2002	UF2003	UF2004	UF2005	UF2006	UF2007	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	50	100	200	400	600	800	1000	V
RMS Reverse Voltage	$V_{R(RMS)}$	35	70	140	280	420	560	700	V
Average Rectifier Forward Current Per Leg T <sub>C</sub> =125	I <sub>F(AV)</sub>	2.0							Α
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions half-ware, single phase, 60Hz)	I <sub>FSM</sub>	60						Α	
Maximum Instantaneous Forward Voltage ( $I_F = 1.0 \text{ Amp } T_C = 25$ )	$V_{F}$	1.0 1.3				1.7			V
Maximum Instantaneous Reverse Current ( Rated DC Voltage, $T_C = 25$ ) ( Rated DC Voltage, $T_C = 125$ )	I <sub>R</sub>	5.0 100						uA	
Reverse Recovery Time ( $I_F = 0.5 \text{ A}$ , $I_R = 1.0$ , $I_{rr} = 0.25 \text{ A}$ )	T <sub>rr</sub>	50					75		ns
Typical Junction Capacitance (Reverse Voltage of 4 volts & f=1 MHz)	C <sub>j</sub>	50				30			pF
Typical Thermal Resistance	$R_{\thetajA}$	25							/W
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-65 to +150							

# UF2001 Thru UF2007

# FIG-1 TYPICAL FORWARD CHARACTERISITICS

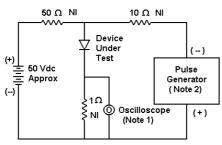


#### FIG-2 TYPICAL REVERSE CHARACTERISTICS



PERCENT OF PEAK REVERSE VOLTAGE (%)

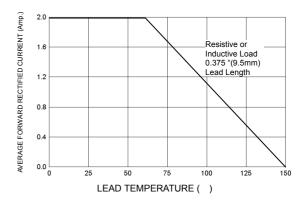
8.3 ms Single Half Sine Wave



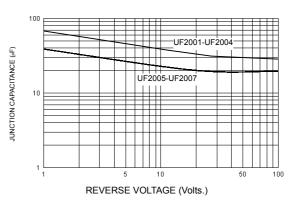
#### Notes:

- 1. Rise Time = 7 ns max. Input Impedance =1 M  $\Omega$  , 22 pF
- 2. Rise Time = 10 ns max. Input Impedance =  $50 \Omega$

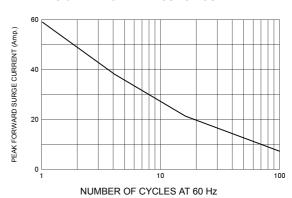
#### FIG-3 FORWARD CURRENT DERATING CURVE



# FIG-4TYPICAL JUNCTION CAPACITANCE



#### FIG-5PEAK FORWARD SURGE CURRENT



-0.25A

Set time base for 20/50 ns/cm

FIG-6 Reverse Recovery Time Characteristic and Test Circuit Diagram

-1.0A



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